

Form PTO-1449 U.S. DEPARTMENT OF COMMERCE (REV. 7-80) PATENT AND TRADEMARK OFFICE		Atty. Docket No. YOR920010308US3 (16315B)		Serial N . Unassigned			
LIST OF PRIOR ART CITED BY APPLICANT		Applicant Jack O. Chu, et al.					
(Use several sheets if necessary)		Filing Date Herewith		Group Unassigned			
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL*		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FLING DATE (if appropriate)
<i>[initials]</i>	AA	5,906,680	5/25/1999	Meyerson			
<i>[initials]</i>	AB	6,190,975	2/2001	Kubo et al			
		2001/0160605	10/2002	Kanazawa et al.;			
		5,683,934	11/1997	Candelaria et al			
		2002/0016085	2/2002	Huang et al			
		6,306,211	10/2001	Takahashi et al.			
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION
							YES
							NO
OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)							
		E. Kasper, et al. "Growth of 100 Ghz SiGe-Heterobipolar Transistor (HBT) Structures," Jpn J App Phys, Vol. 33 Pt. 1, No. 4B, April 1994, pp. 2415-2418; <i>not prior art</i>					
		<i>or at least not in title or abstract of fig.</i>					
		H.J. Osten et al. " in the paper entitled "Carbon Doped SiGe Heterojunction Bipolar Transistors for High Frequency Application," IEEE BCTM 7.1, 1999, pp. 109-116;					
EXAMINER <i>J. MONDT</i>		DATE CONSIDERED		4/29/05			
* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							